

N-Channel 30 V (D-S) MOSFET

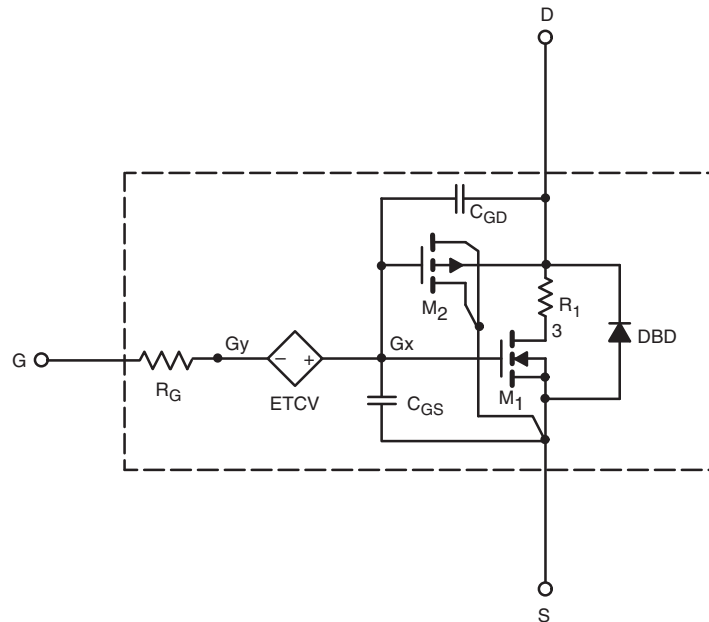
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the - 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



Note

- This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

SPICE Device Model Si3424CDV

Vishay Siliconix

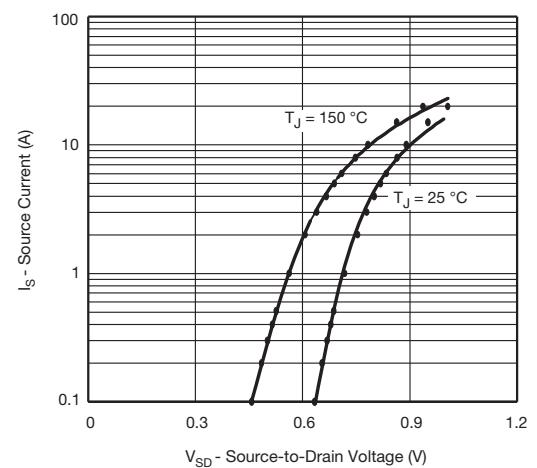
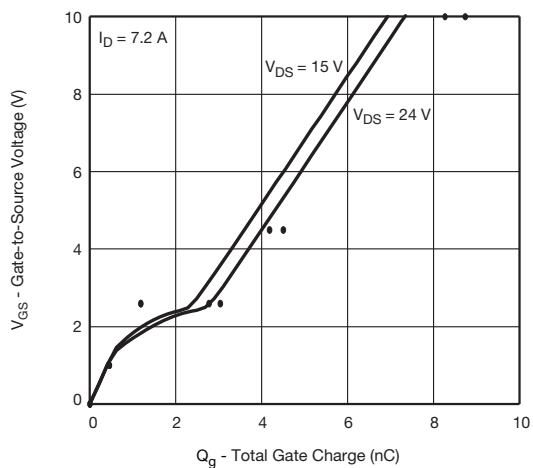
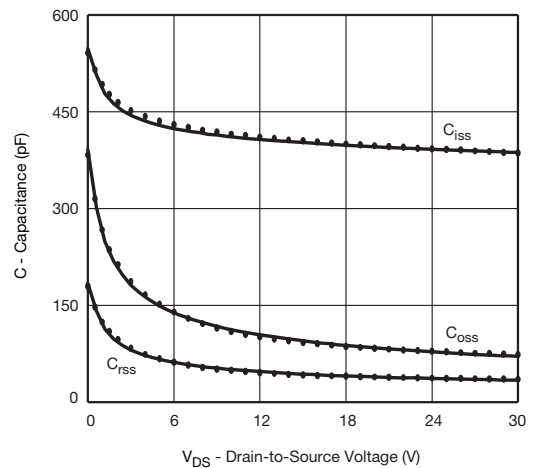
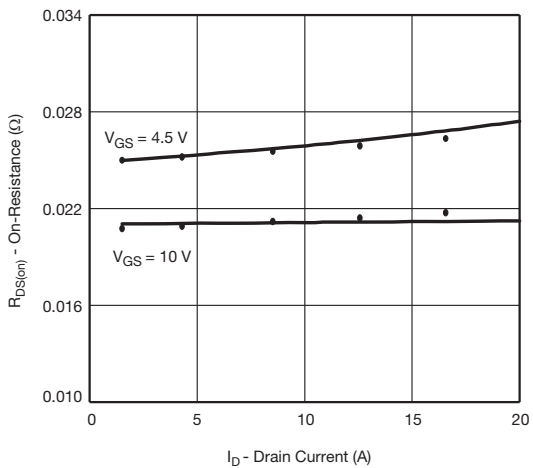
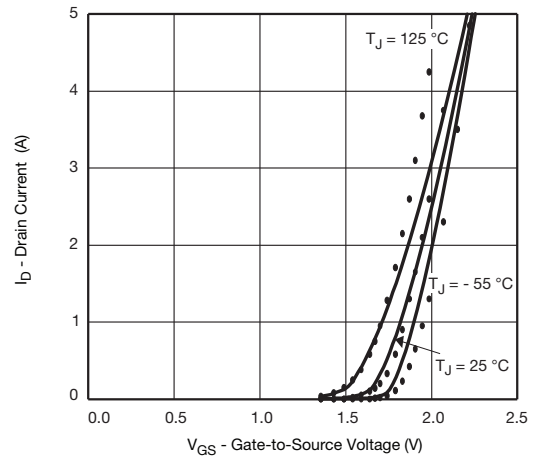
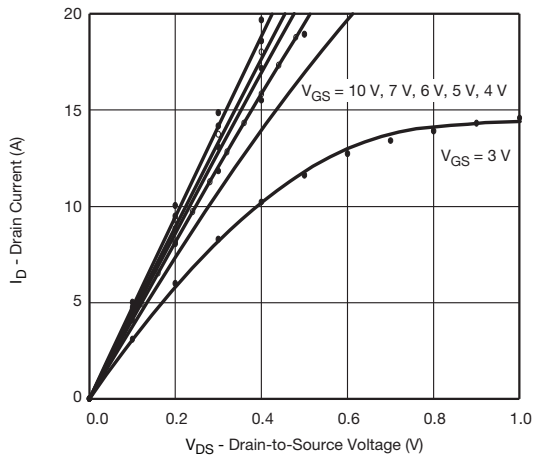


SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	1.2	-	V
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 10\ \text{V}, I_D = 7.2\ \text{A}$	0.021	0.021	Ω
		$V_{DS} = 4.5\ \text{V}, I_D = 6.5\ \text{A}$	0.025	0.026	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 15\ \text{V}, I_D = 7.2\ \text{A}$	14	17	S
Diode Forward Voltage	V_{SD}	$I_S = 5.7\ \text{A}$	0.83	0.80	V
Dynamic^b					
Input Capacitance	C_{iss}	$V_{DS} = 15\ \text{V}, V_{GS} = 0\ \text{V}, f = 1\ \text{MHz}$	402	405	pF
Output Capacitance	C_{oss}		94	92	
Reverse Transfer Capacitance	C_{rss}		43	42	
Total Gate Charge	Q_g	$V_{DS} = 15\ \text{V}, V_{GS} = 10\ \text{V}, I_D = 7.2\ \text{A}$	7.1	8.3	nC
		$V_{DS} = 15\ \text{V}, V_{GS} = 4.5\ \text{V}, I_D = 7.2\ \text{A}$	3.7	4.2	
Gate-Source Charge	Q_{gs}	$V_{DS} = 15\ \text{V}, V_{GS} = 4.5\ \text{V}, I_D = 7.2\ \text{A}$	1.2	1.2	
Gate-Drain Charge	Q_{gd}	$V_{DS} = 15\ \text{V}, V_{GS} = 4.5\ \text{V}, I_D = 7.2\ \text{A}$	1.6	1.6	

Notes

- a. Pulse test; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\ \%$.
- b. Guaranteed by design, not subject to production testing.

COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Note

- Dots and squares represent measured data.



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